March 1998

DM74ALS652/74ALS652-1 Octal 3-STATE

Bus Transceiver and Register

FAIRCHILD

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General Description

This device incorporates an octal transceiver and an octal D-type register configured to enable transmission of data from bus to bus or internal register to bus.

This bus transceiver features totem-pole 3-STATE outputs designed specifically for driving highly-capacitive or relatively low-impedance loads. The high-impedance state and increased high level logic drive provide this device with the capability of being connected directly to and driving the bus lines in a bus organized system without need for interface or pull-up components. They are particularly attractive for implementing buffer registers, I/O ports, bidirectional bus drivers, and working registers.

The 'ALS652-1 version features the same performance as the standard versions, with the addition of increased current drive capability to meet the current requirements of various bus architectures. For all ALS-1 products, the recommended maximum $\rm I_{OL}$ is increased to 48 mA.

The registers in the 'ALS652 are edge-triggered D-type flip-flops. On the positive transition of the clock (CAB or CBA), the input data is stored into the appropriate register. The CAB input controls the transfer of data into the A register and the CBA input controls the B register.

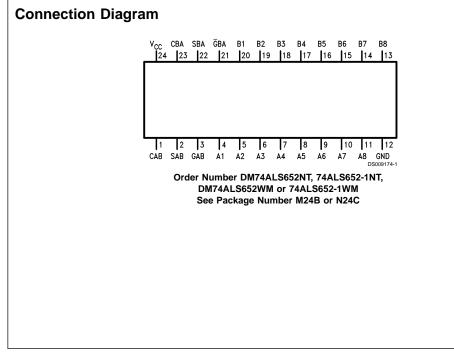
The SAB and SBA control pins are provided to select whether real-time data or stored data is transferred. A low in-

put level selects real-time data and a high level selects stored data. The select controls have a "make before break" configuration to eliminate a glitch which would normally occur in a typical multiplexer during the transition between stored and real-time data.

The enable (GAB and $\overline{G}BA$) control pins provide four modes of operation: real-time data transfer from bus A to B, real-time data transfer from bus B to A, real-time bus A and/or B data transfer to internal storage, or internal stored data transfer to bus A and/or B.

Features

- Maximum I_{OL} increased to 48 mA for 'ALS652-1product
- Switching specifications at 50 pF
- Switching specifications guaranteed over full temperature and V_{CC} range
- Advanced oxide-isolated, ion-implanted Schottky TTL process
- 3-STATE buffer-type outputs drive bus lines directly
- Independent registers and enables for A and B buses
- Multiplexed real-time and stored data



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| Absolute Maximum | Ratings (Note 2) |
|------------------|------------------|
|------------------|------------------|

| Supply Voltage | 7V | Storage Temperature Range | -65°C to +150°C |
|--------------------------------|------|---------------------------|-----------------|
| Input Voltage | 7 V | Typical θ _{JA} | |
| | | N Package | 44.5°C/W |
| Control Inputs | 7V | 0 | 80 F°C/M/ |
| I/O Ports | 5.5V | M Package | 80.5°C/W |
| Operating Free-Air Temperature | | | |

Range

0°C to +70°C

Recommended Operating Conditions

| Symbol | Parameter | DM74 | Units | | | |
|------------------|------------------------------------|----------------|-------|-----|-----|-----|
| | | | Min | Nom | Max | 1 |
| V _{cc} | Supply Voltage | Supply Voltage | | | | V |
| V _{IH} | High Level Input Voltage | | 2 | | | V |
| V _{IL} | Low Level Input Voltage | | | | 0.8 | V |
| I _{OH} | High Level Output Current | | | | -15 | mA |
| I _{OL} | Low Level Output Current | ALS652 | | | 24 | mA |
| | | ALS652-1 | | | 48 | 1 |
| f _{CLK} | Clock Frequency | | 0 | | 40 | MHz |
| t _{vv} | Pulse Duration, Clocks Low or High | า | 12.5 | | | ns |
| t _{su} | Data Setup Time, A before CAB or | | 10↑ | | | ns |
| | B before CBA (Note 3) | | | | | |
| t _H | Data Hold Time, A after CAB or | | 0↑ | | | ns |
| | B after CBA (Note 3) | | | | | |
| T _A | Free Air Operating Temperature | | 0 | | 70 | °C |

Note 1: This product meets application requirements of 500 temperature cycles from -65°C to +150°C.

Note 2: The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the "Electrical Characteristics" table are not guaranteed at the absolute maximum ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 3: \uparrow = with reference to the low to high transition of the respective clock.

Electrical Characteristics

over recommended free air temperature range

| Symbol | Parameter | Test | Min | Тур | Max | Units | |
|-----------------|--------------------------|--|-------------------------------------|---------------------|------|-------|----|
| VIK | Input Clamp Voltage | $V_{CC} = Min, I_I = -18 \text{ mA}$ | | | | -1.2 | V |
| V _{он} | High Level Output | V _{CC} = 4.5V to 5.5V | I _{OH} = -0.4 mA | V _{CC} – 2 | | | |
| | Voltage | V _{CC} = Min | I _{OH} = -3 mA | 2.4 | 3.2 | | V |
| | | | I _{OH} = Max | 2 | | | 1 |
| Vol | Low Level Output | V _{CC} = Min | I _{OL} = 12 mA | | 0.25 | 0.4 | |
| | Voltage | | I _{OL} = 24 mA | | 0.35 | 0.5 | V |
| | | | I _{OL} = 48 mA | | 0.35 | 0.5 | 1 |
| l _i | Input Current at Max | V _{CC} = Max | I/O Ports, V _I = 5.5V | | | 100 | μA |
| | Input Voltage | | Control Inputs, V _I = 7V | | | 100 | 1 |
| I _{IH} | High Level Input Current | V _{CC} = Max, V _I = 2.7\ | /, (Note 4) | | | 20 | μA |
| I _{IL} | Low Level Input | V _{CC} = Max, | Control Inputs | | | -200 | μA |
| | Current | $V_{I} = 0.4V$ (Note 4) | I/O Ports | | | -200 | 1 |
| I _o | Output Drive Current | V _{CC} = Max, V _O = 2.2 | 5V | -30 | | -112 | mA |
| I _{cc} | Supply Current | V _{CC} = Max | Outputs High | | 47 | 76 | |
| | | | Outputs Low | | 55 | 88 | mA |
| | | | Outputs Disabled | | 55 | 88 | 1 |

Note 4: For I/O ports the 3-STATE output currents (I_{OZH} and I_{OZL}) are included in the I_{IH} and I_{IL} parameters.

| Symbol | Parameter | Conditions | From (Input) To (Output) | DM744 74AL | Units | |
|------------------|--------------------------|---------------------------------|-----------------------------|---------------|-------|----|
| | | | | Min Max | | |
| t _{PLH} | Propagation Delay Time | V _{CC} = 4.5V to 5.5V, | CBA or CAB | 10 | 30 | ns |
| | Low to High Level Output | C _L = 50 pF, | to A or B | | | |
| t _{PHL} | Propagation Delay Time | $R_1 = R_2 = 500\Omega,$ | CBA or CAB | 5 | 17 | ns |
| | High to Low Level Output | $T_A = Min \text{ to } Max$ | to A or B | | | |
| t _{PLH} | Propagation Delay Time | | A or B to | 5 | 18 | ns |
| | Low to High Level Output | | B or A | | | |
| t _{PHL} | Propagation Delay Time | | A or B to | 3 | 12 | ns |
| | High to Low Level Output | | B or A | | | |
| t _{PLH} | Propagation Delay Time | | | | | |
| | Low to High Level Output | | SBA or SAB | 12 | 35 | ns |
| | (with A or B | | to A or B | | | |
| | Low) (Note 6) | | | | | |
| t _{PHL} | Propagation Delay Time | | | | | |
| | High to Low Level Output | | SBA or SAB | 6 | 20 | ns |
| | (with A or B | | to A or B | | | |
| | Low) (Note 6) | | | | | |
| t _{PLH} | Propagation Delay Time | | | | | |
| | Low to High Level Output | | SBA or SAB | 6 | 25 | ns |
| | (with A or B | | to A or B | | | |
| | High) (Note 6) | | | | | |
| t _{PHL} | Propagation Delay Time | | | | | |
| | High to Low Level Output | | SBA or SAB | 5 | 20 | ns |
| | (with A or B | | to A or B | | | |
| | High) (Note 6) | | | | | |
| t _{PZH} | Output Enable Time | | GBA to | 3 | 17 | ns |
| | to High Level Output | | A | | | |
| t _{PZL} | Output Enable Time | | GBA to | 5 | 18 | ns |
| | to Low Level Output | | A | | | |
| t _{PHZ} | Output Disable Time | | GBA to | 1 | 10 | ns |
| | from High Level Output | | A | | | |
| t _{PLZ} | Output Disable Time | | GBA to | 2 | 16 | ns |
| | from Low Level Output | | A | | | |
| t _{PZH} | Output Enable Time | | GAB to | 6 | 22 | ns |
| | to High Level Output | | В | | | |
| t _{PZL} | Output Enable Time | | GAB to | 6 | 18 | ns |
| | to Low Level Output | | В | | | |
| t _{PHZ} | Output Disable Time | | GAB to | 1 | 10 | ns |
| | from High Level Output | | В | | | |
| t _{PLZ} | Output Disable Time | | GAB to | 2 | 16 | ns |
| | from Low Level Output | | В | | | |

Note 5: See Section 1 for test waveforms and output load.

Note 6: These parameters are measured with the internal output state of the storage register opposite to that of the bus input.

Function Table

| 14 | | | 510 | | | | | |
|-----|--------|----------|-----|------------|------------|-----------------------|---------------|---------------------------|
| | Inputs | | | Data I/O | (Note 7) | Operation or Function | | |
| GAB | GBA | CAB | СВА | SAB | SBA | A1 thru A8 | B1 thru B8 | |
| Х | Н | ↑ | H/L | Х | Х | Input | Not Specified | Store A, Hold B |
| L | Х | H/L | ↑ | Х | Х | Not Specified | Input | Store B, Hold A |
| L | Н | ↑ | ↑ | Х | Х | Input | Input | Store A and B Data |
| L | Н | H/L | H/L | Х | Х | Input | Input | Isolation, Hold Storage |
| L | L | Х | Х | Х | L | Output | Input | Real-Time B Data to A Bus |
| L | L | Х | H/L | Х | Н | Output | Input | Stored B Data to A Bus |
| Н | Н | Х | Х | L | Х | Input | Output | Real-Time A Data to B Bus |
| Н | Н | ↑ | ↑ | Х | Х | Input | Output | Stored A Data to B Bus |
| Н | Н | ↑ | ↑ | X (Note 8) | Х | Input | Output | Store A in both Registers |
| L | L | ↑ | | Х | X (Note 8) | Output | Input | Store B in both Registers |

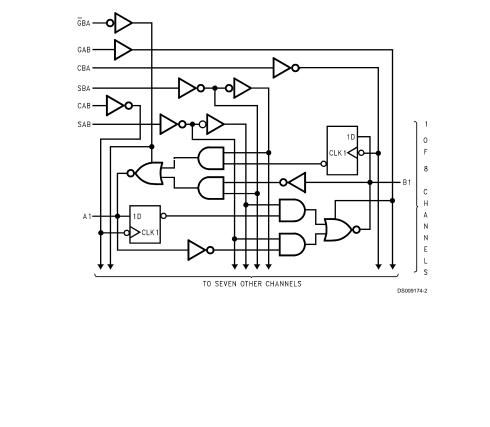
Note 7: The data output functions may be enabled or disabled by various signals at the G and DIR inputs. Data input functions are always enabled, i.e., data at the bus pins will be stored on every low-to-high transition on the clock inputs.

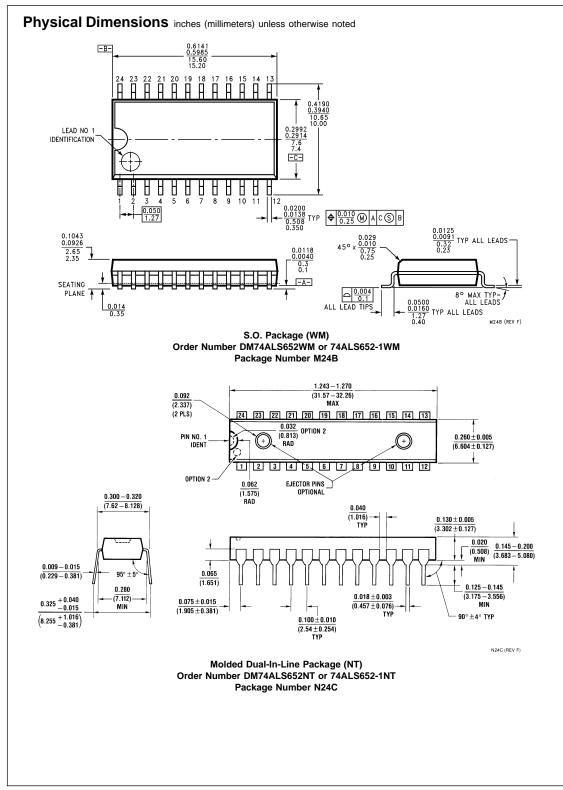
Note 8: Select control = L; clocks can occur simultaneously

Select control = H; clocks must be staggered in order to load both registers.

H = High Logic Level, L = Low Logic Level, X = Don't Care (Either Low or High Logic Levels, including transitions), H/L = Either Low or High Logic Level excluding transitions, ↑ = Positive-going edge of pulse.

Logic Diagram





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